

# 3 V SILICON RFIC FREQUENCY UPCONVERTER

# **UPC8106TB**

#### **FEATURES**

#### · RECOMMENDED OPERATING FREQUENCY:

fRFout = 0.4 GHz to 2.0 GHz fIFin = 100 MHz to 400 MHz

· SUPPLY VOLTAGE:

Vcc = 2.7 to 5.5 V

# HIGH DENSITY SURFACE MOUNTING:

6 pin super mini mold package

#### LOW CARRIER LEAKAGE:

Due to double balanced mixer

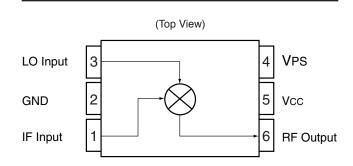
BUILT-IN POWER SAVE FUNCTION

#### **DESCRIPTION**

NEC's UPC8106TB is a silicon RFIC designed as a frequency upconverter for cellular/cordless telephone transmitter stages and features improved intermodulation. This device is housed in a 6 pin super mini mold or SOT-363 package making it ideal for reducing system size. The UPC8106TB is manufactured using NEC's 20 GHz ft NESAT™III silicon bipolar process.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

#### INTERNAL BLOCK DIAGRAM



#### **APPLICATION**

· CELLULAR/CORDLESS TELEPHONE

#### **ELECTRICAL CHARACTERISTICS**

 $(TA = 25^{\circ}C, VCC = VRFout = 3 \text{ V}, fIFin = 240 \text{ MHz}, PLOin = -5 \text{ dBm}, VPS \ge 2.7 \text{ V} unless otherwise specified})$ 

	PART NUMBER PACKAGE OUTLINE	UPC8106TB S06			
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
Icc	Circuit Current at VPS ≥ 2.7 V VPS = 0 V	mA μA	4.5	9	13.5 10
CG	Conversion Gain at fRFout = 0.9 GHz, PIFin = -30 dBm fRFout = 1.9 GHz, PIFin = -30 dBm	dB dB	6 4	9 7	12 10
Psat	Saturated Output Power at fRFout = 0.9 GHz, PIFin = 0 dBm fRFout = 1.9 GHz, PIFin = 0 dBm	dBm dBm	-4 -6.5	-2 -4	
OIP3	Output Third-Order Intercept Point at  fIFin1 = 240.0 MHz fIFin2 = 240.4 MHz fRFout = 0.9 GHz fRFout = 1.9 GHz	dBm dBm		+5.5 +2.0	
IMз	Third-Order Intermodulation Level at  fIFin1 = 240 MHz  fIFin2 = 240.4 MHz  PIFin = -20 dBm  fRFout = 0.9 GHz  fRFout = 1.9 GHz	dBc dBc		-31 -30	
NF	SSB Noise Figure, fRFout = 0.9 GHz	dB		8.5	
TPS(RISE)	Power Save Rise Time at Vps: GND→Vcc	μS		2.0	
TPS(FALL)	Power Save Fall Time at VPS: VCC → GND	μS		2.0	

\_California Eastern Laboratories

# ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage Pins 5 & 6	V	6.0
VPS	Power Save Voltage	V	6.0
Рт	Total Power Dissipation <sup>2</sup>	mW	200
Тор	Operating Temperature	°C	-40 to +85
Тѕтс	Storage Temperature	°C	-55 to +150
Pin	Input Power	dBm	+10

#### Notes:

- 1. Operation in excess of any one of these parameters may result in permanent damage.
- 2. Mounted on a 50 x  $\overline{50}$  x 1.6 mm epoxy glass PWB (TA = +85°C).

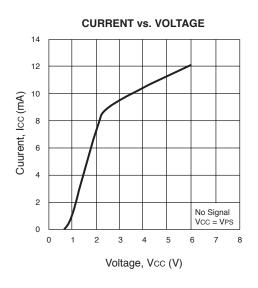
# RECOMMENDED OPERATING CONDITIONS

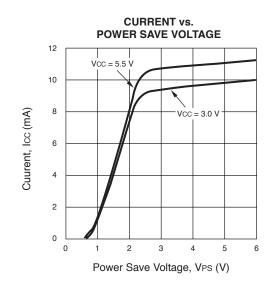
SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage <sup>1</sup>	V	2.7	3.0	5.5
Тор	Operating Temperature	°C	-40	+25	+85
PLO	LO Input Level <sup>2</sup>	dBm	-10	-5	0
fRFout	RF Output Frequency <sup>3</sup>	GHz	0.4		2.5
fIFin	IF Input Frequency	MHz	100		400

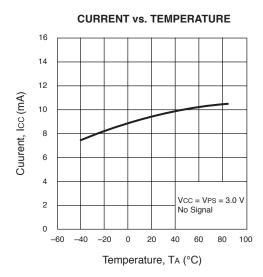
#### Notes

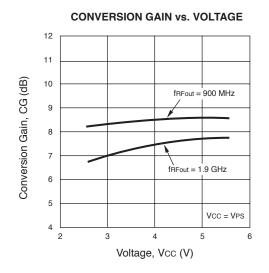
- 1. The same voltage should be supplied to pin 5 and 6.
- 2.  $Zs = 50 \Omega$  (without matching).
- 3. With external matching circuit.

# TYPICAL PERFORMANCE CURVES (TA = +25°C, VCC = VRFout)

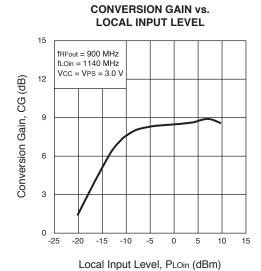


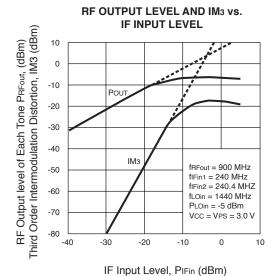




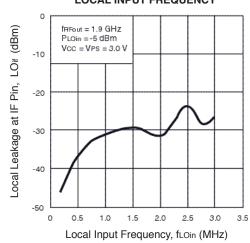


# TYPICAL PERFORMANCE CURVES (TA = +25°C, VCC = VRFout)

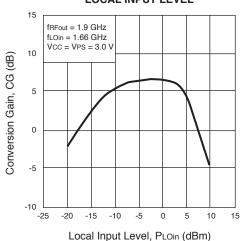




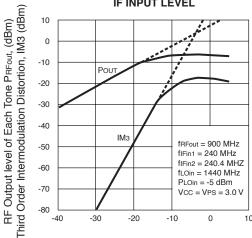
# LOCAL LEAKAGE AT IF PIN vs. LOCAL INPUT FREQUENCY



#### CONVERSION GAIN vs. LOCAL INPUT LEVEL

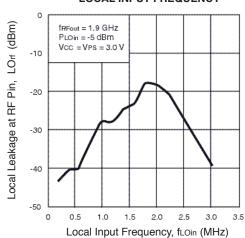


# RF OUTPUT LEVEL AND IM3 vs. IF INPUT LEVEL

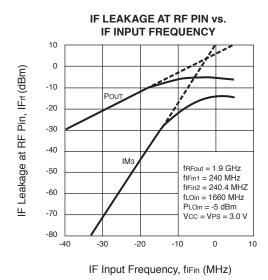


IF Input Level, PIFin (dBm)

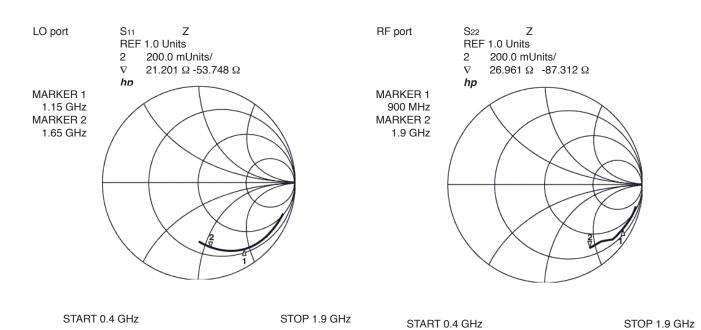
#### LOCAL LEAKAGE AT RF PIN vs. LOCAL INPUT FREQUENCY



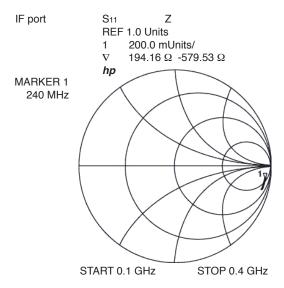
# TYPICAL PERFORMANCE CURVES (TA = +25°C, VCC = VRFout)



# S-PARAMETERS FOR EACH PORT (Vcc = Vps = VRFout = 3.0 V)



# S-PARAMETERS FOR EACH PORT (VCC = VPS = VRFout = 3.0 V)



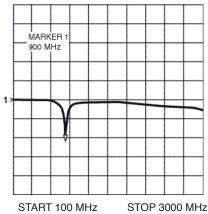
## S-PARAMETERS FOR MATCHED RF OUTPUT

(Vcc = Vps = VRFout = 3.0 V) - with TEST CIRCUITS 1 and 2 - (S22 data is monitored at RF connector on board.)

900 MHz (LC-matched) in test circuit  $S_{11}log\ MAG$ 

REF 0.0 dB 1 10.0 dB/ V -19.567 dB

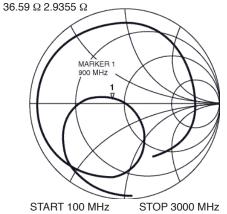
hp



S22

REF 1.0 Units 1 200.0 mUnits/ ∇ 36.59 Ω 2.935

hр

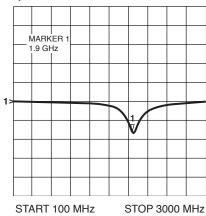


1.9 GHz (LC-matched) in test circuit

S22 log MAG

REF 0.0 dB 1 10.0 dB/ ∇ -15.213 dB

hp

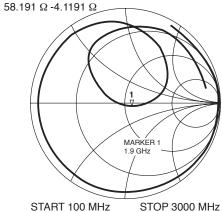


S22

REF 1.0 Units

1 200.0 mUnits/ ∇ 58.191 Ω -4.11

hp



# **PIN FUNCTIONS**

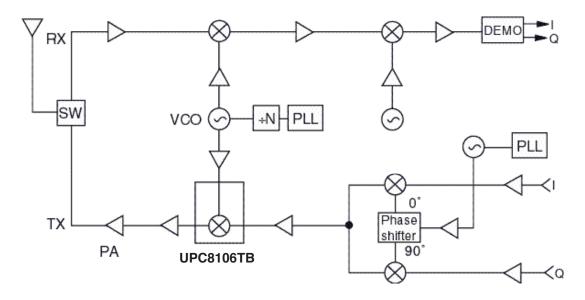
Pin No.	Symbol	Supply Voltage (V)	Pin¹ Voltage (V)	Description	Equivalent Circuit
1	IF Input	_	1.3	This pin is the IF input to the double bal- anced mixer. The input is a high imped- ance.	
2	GND	0	_	GND pin. Ground pattern on the board should be as wide as possible. Trace length should be kept as short as possible to minimize ground impedance.	3
3	LOIN	-	2.4	LO input pin. Recommended input level is -10 to 0 dBm.	
5	Vcc	2.7 to 5.5	-	Supply voltage pin.	
6	RF Output	2.7 to 3.6	_	This pin is the RF output. This pin is designed as an open collector. Due to the high impedance output, this pin requires an external LC matching circuit.	
4	VPS	Vcc/GND	-	Power save control pin. Bias controls operation as follows:    Pin Bias   Control     Vcc   ON     GND   Power Save	Vcc

#### Note:

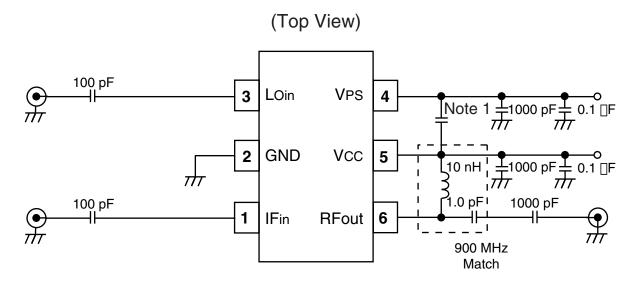
<sup>1.</sup> Each pin voltage is measured with  $Vcc = VPs = VRFout = 3.0 \ V$ 

# **SYSTEM APPLICATION EXAMPLE**

## **EXAMPLE OF DECT 900 MHz Cordless Phone**



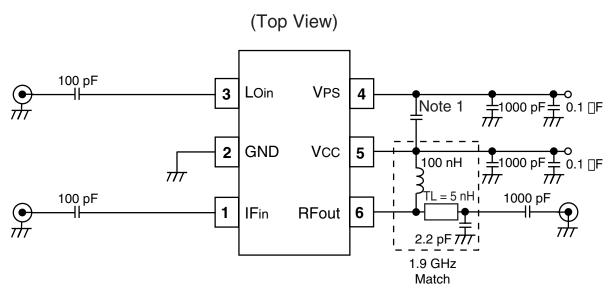
# TEST CIRCUIT 1 (RFOUT = 900 MHz)



#### Note

1. In case of unstable operation, connect 100 pF capacitor between pins 4 and 5.

# TEST CIRCUIT 2 (RFOUT = 1.9 GHz)



#### Note:

1. In case of unstable operation, connect 100 pF capacitor between pins 4 and 5.

# **OUTLINE DIMENSIONS** (Units in mm)

# 2.0±0.1 0.05 3 1.3 0.65 2 0.9 ± 0.1 0.7 0.00 1 0.15 -0.5

#### Note:

All dimensions are typical unless otherwise specified.

#### **ORDERING INFORMATION**

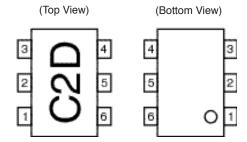
PART NUMBER	QTY
UPC8106TB-E3-A	3K/Reel

#### Note:

Embossed Tape, 8 mm wide,

Pins 1, 2, and 3 face tape perforation side.

## **LEAD CONNECTIONS**



- 1. IF INPUT
- 2. GND
- 3. LO INPUT
- 4. POWER SAVE
- 5. Vcc
- 6. RF OUTPUT

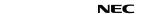
Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

California Eastern Laboratories, Your source for NEC RF, Microwave, Optoelectronic, and Fiber Optic Semiconductor Devices.
4590 Patrick Henry Drive • Santa Clara, CA 95054-1817 • (408) 988-3500 • FAX (408) 988-0279 • www.cel.com

DATA SUBJECT TO CHANGE WITHOUT NOTICE

03/31/2008





4590 Patrick Henry Drive Santa Clara, CA 95054-1817 Telephone: (408) 919-2500

Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	ry < 1000 PPM Not Detec		etected	
Cadmium < 100 PPM		Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.